NSN 5961-01-103-7825

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-103-7825 **Inclosure Material:** Ceramic **Overall Length:** 0.170 inches **Overall Diameter:** 0.240 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 3.5 breakdown voltage, emitter-to-base, collector open and 45.0 breakdown voltage, collector-to-base, emitter open and 50.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter **Current Rating Per Characteristic:** 0.50 milliamperes source cutoff current **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** voltage; junction pattern arrangement: npn **Precious Material And Location:** External surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 4 flange Shelf Life: N/a **Unit Of Measure: Demilitarization:**